

Product Summary

| | | |
|---------------|-----------------|-------|
| $V_{(BR)DSS}$ | $R_{DS(on)TYP}$ | I_D |
| 150V | 9mΩ@10V | 90A |



合肥矽普半导体

Siliup Semiconductor Technology Co., Ltd

技术 品质 服务

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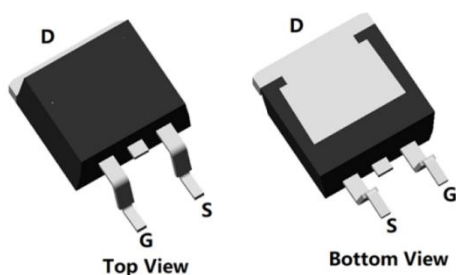
Feature

- Fast Switching
- Low Gate Charge and Rdson
- Advanced Split Gate Trench Technology
- 100% Single Pulse avalanche energy Test

Applications

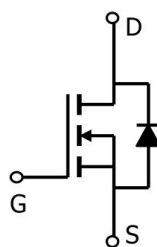
- PWM Application
- Hard switched and high frequency circuits
- Power Management

Package

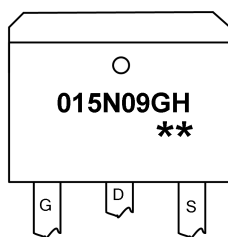


TO-263(1:G 2:D 3:S)

Circuit diagram



Marking



015N09GH : Device Code
****** : Week Code

Order Information

| Device | Package | Unit/Tape |
|--------------|---------|-----------|
| SP015N09GHTD | TO-263 | 800 |

**Absolute maximum ratings (Ta=25°C, unless otherwise noted)**

| Parameter | Symbol | Rating | Units |
|--------------------------------------------|-----------------|------------|-------|
| Drain-Source Voltage | V_{DS} | 150 | V |
| Gate-Source Voltage | V_{GS} | ± 20 | V |
| Continuous Drain Current (Tc=25°C) | I_D | 90 | A |
| Continuous Drain Current (Tc=100°C) | I_D | 60 | A |
| Pulsed Drain Current | I_{DM} | 360 | A |
| Single Pulse Avalanche Energy ¹ | E_{AS} | 462 | mJ |
| Power Dissipation (Tc=25°C) | P_D | 180 | W |
| Thermal Resistance Junction-to-Case | $R_{\theta JC}$ | 0.69 | °C/W |
| Storage Temperature Range | T_{STG} | -55 to 150 | °C |
| Operating Junction Temperature Range | T_J | -55 to 150 | °C |

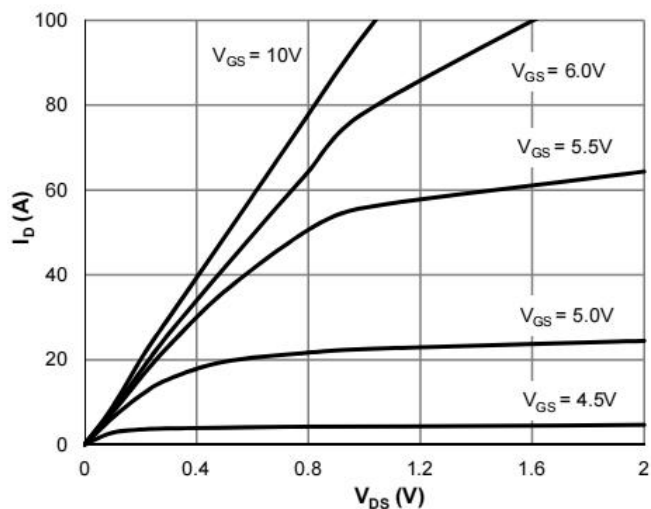
Electrical characteristics (Ta=25°C, unless otherwise noted)

| Characteristics | Symbol | Test Condition | Min | Typ | Max | Unit |
|-----------------------------------------|--------------|------------------------------------------------|-----|------|-----------|------------|
| Static Characteristics | | | | | | |
| Drain-Source Breakdown Voltage | BV_{DSS} | $I_D = 250\mu A, V_{GS} = 0V$ | 150 | - | - | V |
| Drain Cut-Off Current | I_{DSS} | $V_{DS} = 120V, V_{GS} = 0V$ | - | - | 1 | μA |
| Gate Leakage Current | I_{GSS} | $V_{GS} = \pm 20V, V_{DS} = 0V$ | - | - | ± 0.1 | |
| Gate Threshold Voltage | $V_{GS(th)}$ | $V_{DS} = V_{GS}, I_D = 250\mu A$ | 2.0 | 3.0 | 4.0 | V |
| Drain-Source ON Resistance | $R_{DS(ON)}$ | $V_{GS} = 10V, I_D = 20A$ | - | 9 | 12 | m Ω |
| Dynamic Characteristics | | | | | | |
| Input Capacitance | C_{iss} | $V_{DS}=75V, V_{GS}=0V, f=1MHz$ | - | 3310 | - | pF |
| Output Capacitance | C_{oss} | | - | 268 | - | |
| Reverse Transfer Capacitance | C_{rss} | | - | 9 | - | |
| Total Gate Charge | Q_g | $V_{DS}=75V, V_{GS}=10V, I_D=20A$ | - | 30 | - | nC |
| Gate-Source Charge | Q_{gs} | | - | 17.8 | - | |
| Gate-Drain Charge | Q_{gd} | | - | 7 | - | |
| Switching Characteristics | | | | | | |
| Turn-On Delay Time | $t_{d(on)}$ | $V_{DD}=75V, V_{GS}=10V, R_G=6\Omega, I_D=20A$ | - | 13 | - | nS |
| Rise Time | t_r | | - | 25 | - | |
| Turn-Off Delay Time | $t_{d(off)}$ | | - | 31 | - | |
| Fall Time | t_f | | - | 25 | - | |
| Drain-Source Body Diode Characteristics | | | | | | |
| Source-Drain Diode Forward Voltage | V_{SD} | $I_S = 1A, V_{GS} = 0V$ | - | - | 1.2 | V |
| Maximum Body-Diode Continuous Current | I_S | | - | - | 90 | A |
| Reverse Recovery Time | T_{rr} | $I_S=20A, di/dt=200A/us, T_J=25^{\circ}C$ | - | 78 | - | nS |
| Reverse Recovery Charge | Q_{rr} | | - | 185 | - | nC |

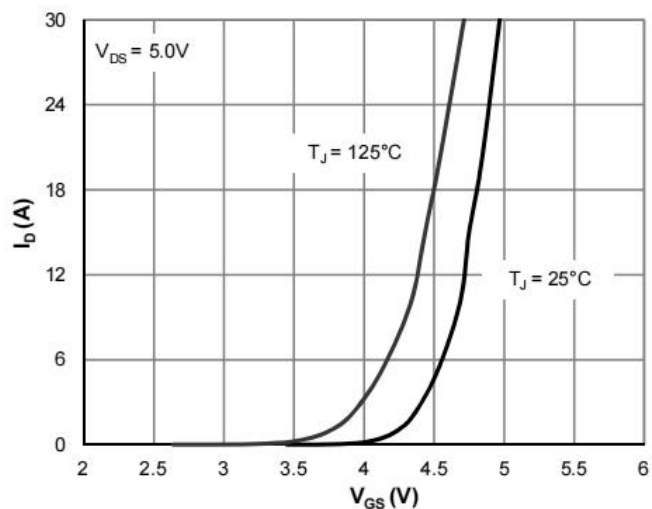
Note :

1. The test condition is $V_{DD} = 50V, V_{GS} = 10V, L = 0.5mH, R_G = 25\Omega$

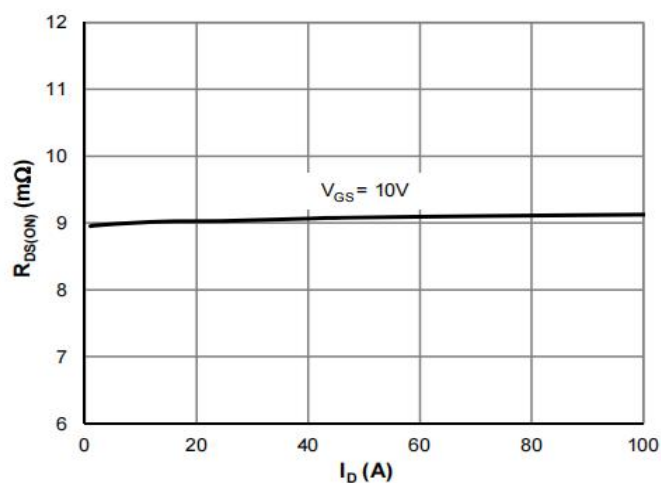
Typical Characteristics



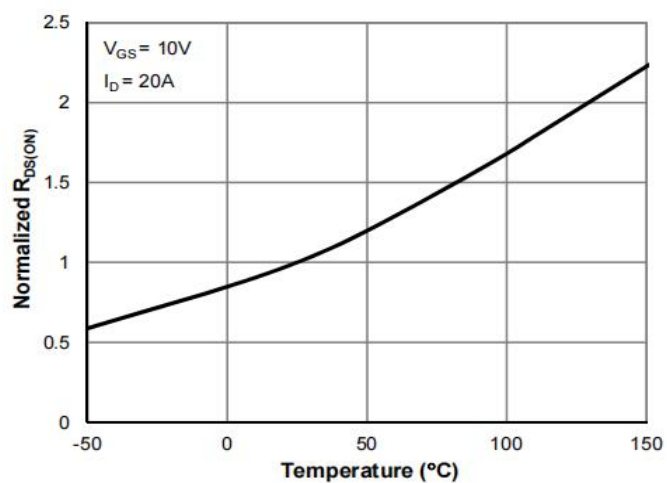
Typical Output Characteristics



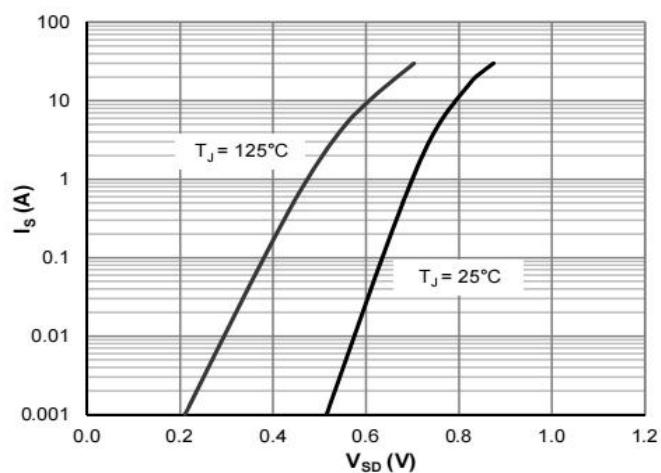
Transfer Characteristics



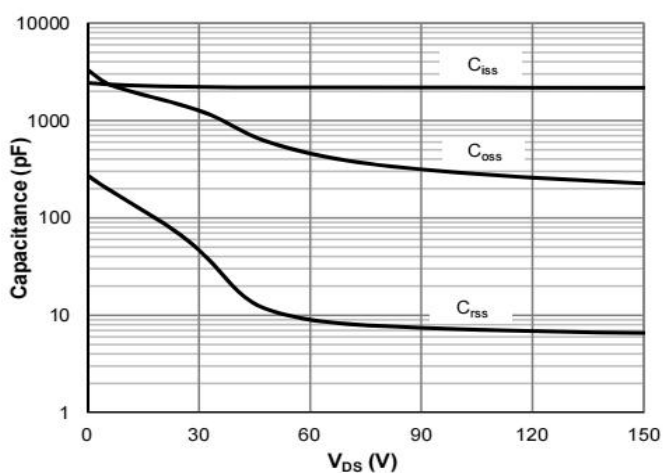
On-Resistance vs. Drain Current



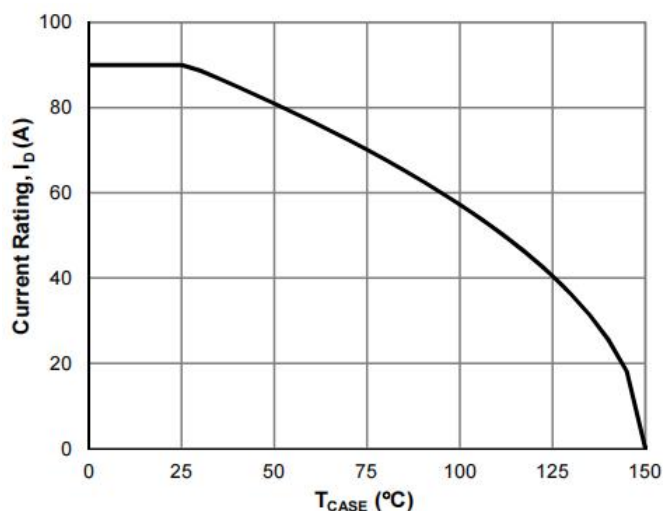
On-Resistance vs. Junction Temperature



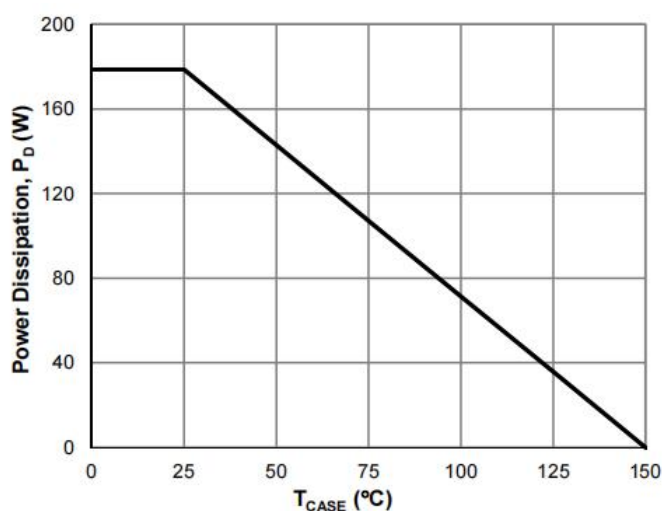
Body-Diode Characteristics



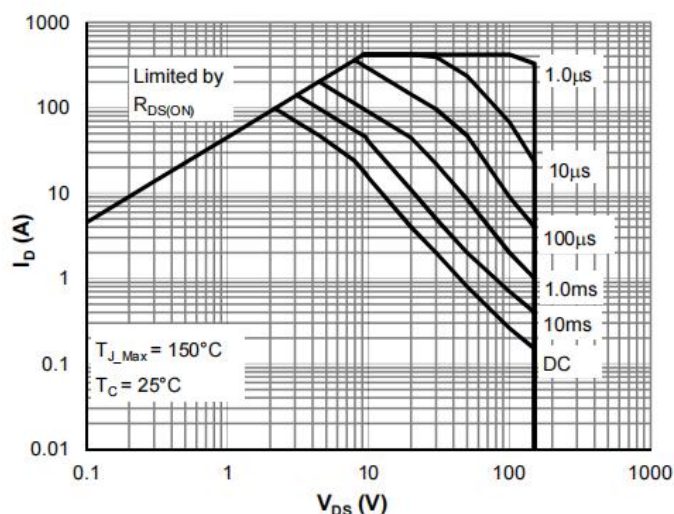
Capacitance Characteristics



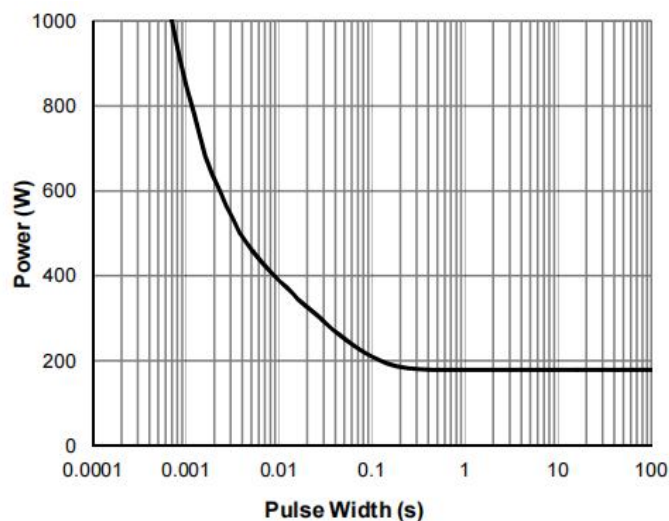
Current De-rating



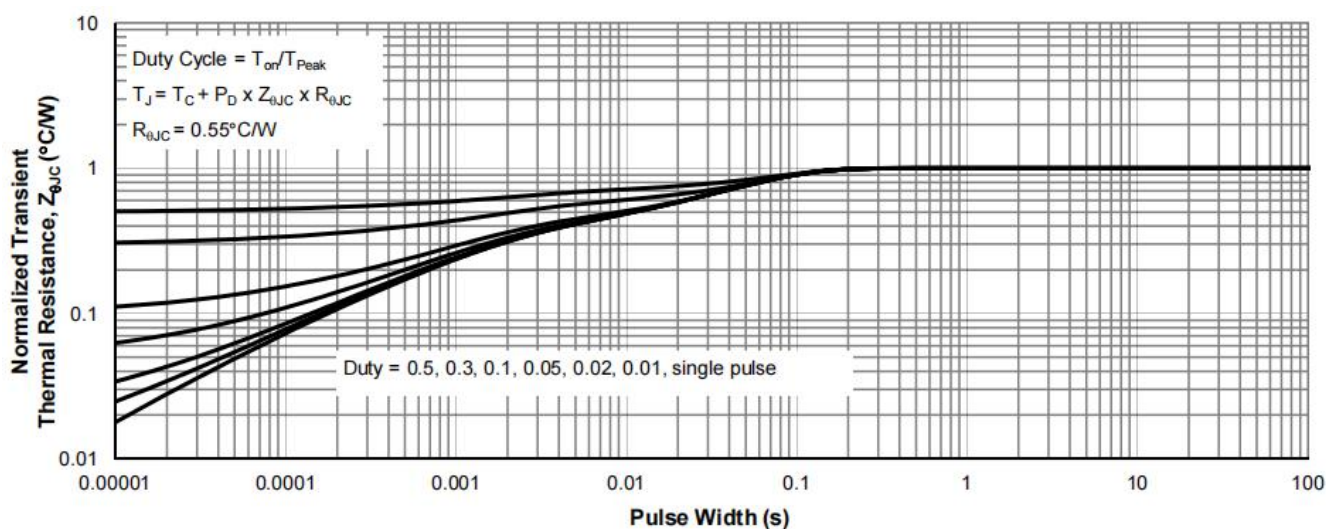
Power De-rating



Maximum Safe Operating Area

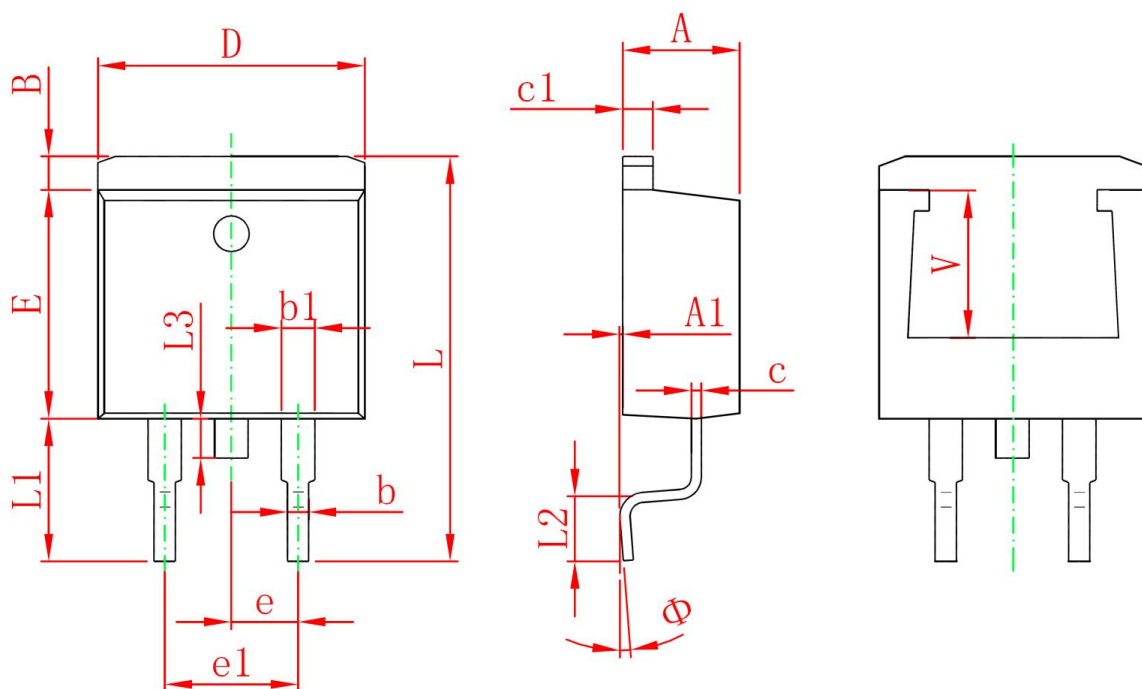


Single Pulse Power Rating, Junction-to-Case



Normalized Maximum Transient Thermal Impedance

TO-263 Package Information



| Symbol | Dimensions In Millimeters | | Dimensions In Inches | |
|--------|---------------------------|--------|----------------------|-------|
| | Min. | Max. | Min. | Max. |
| A | 4.470 | 4.670 | 0.176 | 0.184 |
| A1 | 0.000 | 0.150 | 0.000 | 0.006 |
| B | 1.120 | 1.420 | 0.044 | 0.056 |
| b | 0.710 | 0.910 | 0.028 | 0.036 |
| b1 | 1.170 | 1.370 | 0.046 | 0.054 |
| c | 0.310 | 0.530 | 0.012 | 0.021 |
| c1 | 1.170 | 1.370 | 0.046 | 0.054 |
| D | 10.010 | 10.310 | 0.394 | 0.406 |
| E | 8.500 | 8.900 | 0.335 | 0.350 |
| e | 2.540 TYP. | | 0.100 TYP. | |
| e1 | 4.980 | 5.180 | 0.196 | 0.204 |
| L | 14.940 | 15.500 | 0.588 | 0.610 |
| L1 | 4.950 | 5.450 | 0.195 | 0.215 |
| L2 | 2.340 | 2.740 | 0.092 | 0.108 |
| L3 | 1.300 | 1.700 | 0.051 | 0.067 |
| Φ | 0° | 8° | 0° | 8° |
| V | 5.600 REF. | | 0.220 REF. | |